Low-power 2-input NAND Schmitt trigger Rev. 9.1 — 11 July 2023

Product data sheet

1. General description

The 74AUP1G132 is a single 2-input NAND gate with Schmitt-trigger inputs. Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- · High noise immunity
- Overvoltage tolerant inputs to 3.6 V
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Low noise overshoot and undershoot < 10 % of V_{CC}
- IOFF circuitry provides partial Power-down mode operation
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

3. Applications

- Wave and pulse shaper
- Astable multivibrator
- Monostable multivibrator.

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4. Ordering information

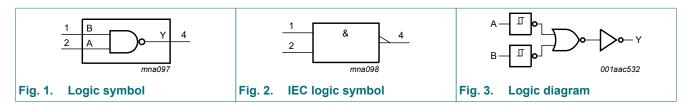
Type number	Package									
	Temperature range	Name	Description	Version						
74AUP1G132GW	-40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	<u>SOT353-1</u>						
74AUP1G132GM	-40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	<u>SOT886</u>						
74AUP1G132GN	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 0.9 × 1.0 × 0.35 mm	<u>SOT1115</u>						
74AUP1G132GS	-40 °C to +125 °C	XSON6	extremely thin small outline package; no leads; 6 terminals; body 1.0 × 1.0 × 0.35 mm	<u>SOT1202</u>						
74AUP1G132GX	-40 °C to +125 °C	X2SON5	plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 × 0.8 × 0.32 mm	<u>SOT1226-3</u>						

5. Marking

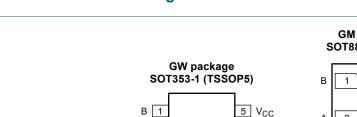
Table 2. Marking	
Type number	Marking code [1]
74AUP1G132GW	aE
74AUP1G132GM	aE
74AUP1G132GN	aE
74AUP1G132GS	aE
74AUP1G132GX	aE

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

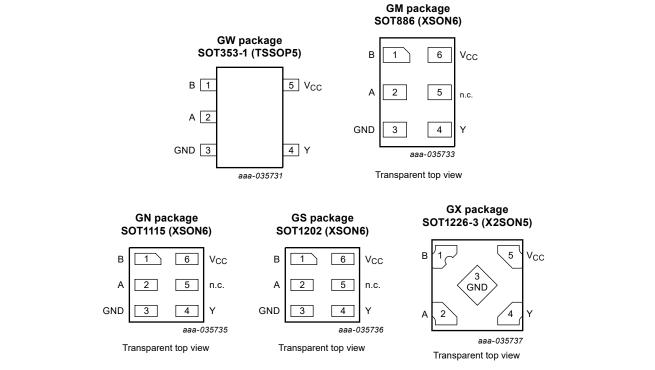
6. Functional diagram



7. Pinning information



7.1. Pinning



7.2. Pin description

Symbol	Pin	Pin			
	TSSOP5 and X2SON5	XSON6			
В	1	1	data input		
A	2	2	data input		
GND	3	3	ground (0 V)		
Y	4	4	data output		
n.c.	-	5	not connected		
V _{CC}	5	6	supply voltage		

8. Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input	Output	
Α	В	Y
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V	-50	-	mA
VI	input voltage	[1]	-0.5	+4.6	V
I _{OK}	output clamping current	V ₀ < 0 V	-50	-	mA
Vo	output voltage	Active mode and Power-down mode [1]	-0.5	+4.6	V
Ι _Ο	output current	$V_{O} = 0 V \text{ to } V_{CC}$	-	±20	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C [2]	-	250	mW

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SOT353-1 (TSSOP5) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT886 (XSON6) package: P_{tot} derates linearly with 3.3 mW/K above 74 °C.

For SOT1115 (XSON6) package: P_{tot} derates linearly with 3.2 mW/K above 71 °C.

For SOT1202 (XSON6) package: Ptot derates linearly with 3.3 mW/K above 74 °C.

For SOT1226-3 (X2SON5) package: P_{tot} derates linearly with 3.0 mW/K above 67 °C.

10. Recommended operating conditions

Table 6.	Table 6. Recommended operating conditions										
Symbol	Parameter	Min	Max	Unit							
V _{CC}	supply voltage		0.8	3.6	V						
VI	input voltage		0	3.6	V						
Vo	output voltage	Active mode	0	V _{CC}	V						
		Power-down mode; V _{CC} = 0 V	0	3.6	V						
T _{amb}	ambient temperature		-40	+125	°C						

11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = 2	25 °C					
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
l _l	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μA
ΔI _{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
Δl _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 V; I_{O} = 0 A; V_{CC} = 3.3 V$ [1]	-	-	40	μA
CI	input capacitance	V_{I} = GND or V_{CC} ; V_{CC} = 0 V to 3.6 V	-	1.1	-	pF
Co	output capacitance	$V_{O} = GND; V_{CC} = 0 V$	-	1.7	-	pF
T _{amb} = -	40 °C to +85 °C					_
V _{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	_	-	V

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.45	V
I _I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
ΔI _{OFF}	additional power-off leakage current	$V_{I} \text{ or } V_{O} = 0 \text{ V to } 3.6 \text{ V;}$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.6	μA
I _{CC}	supply current	$\label{eq:VI} \begin{array}{l} V_{I} = GND \text{ or } V_{CC}; \ I_{O} = 0 \ A; \\ V_{CC} = 0.8 \ V \text{ to } 3.6 \ V \end{array}$	-	-	0.9	μA
ΔI_{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}$ [1]	-	-	50	μA
T _{amb} = -	40 °C to +125 °C	·				
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I _I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_{I} or V_{O} = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μA
ΔI _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 V; I_{O} = 0 A; V_{CC} = 3.3 V$ [1]	-	-	75	μA

[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

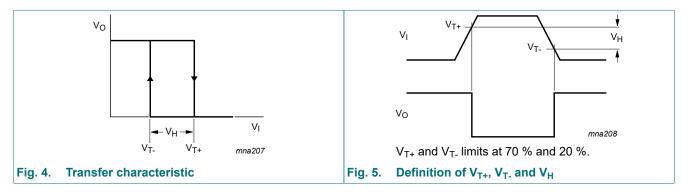
11.1. Transfer characteristics

Table 8. Transfer characteristics

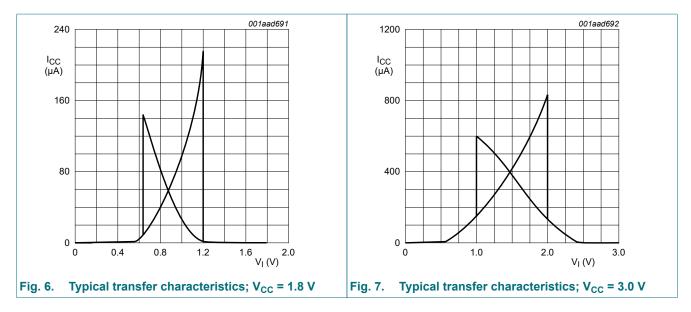
Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 9.

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-	°C to 5 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	1
V _{T+}	positive-going threshold voltage	see <u>Fig. 4</u> and <u>Fig. 5</u>								
		V _{CC} = 0.8 V	0.30	-	0.60	0.30	0.60	0.30	0.62	V
	Voltage	V _{CC} = 1.1 V	0.53	-	0.90	0.53	0.90	0.53	0.92	V
		V _{CC} = 1.4 V	0.74	-	1.11	0.74	1.11	0.74	1.13	V
		V _{CC} = 1.65 V	0.91	-	1.29	0.91	1.29	0.91	1.31	V
		V _{CC} = 2.3 V	1.37	-	1.77	1.37	1.77	1.37	1.80	V
		V _{CC} = 3.0 V	1.88	-	2.29	1.88	2.29	1.88	2.32	V
V _{T-}	negative-going	see <u>Fig. 4</u> and <u>Fig. 5</u>								
	threshold voltage	V _{CC} = 0.8 V	0.10	-	0.60	0.10	0.60	0.10	0.60	V
	voltage	V _{CC} = 1.1 V	0.26	-	0.65	0.26	0.65	0.26	0.65	V
		V _{CC} = 1.4 V	0.39	-	0.75	0.39	0.75	0.39	0.75	V
		V _{CC} = 1.65 V	0.47	-	0.84	0.47	0.84	0.47	0.84	V
		V _{CC} = 2.3 V	0.69	-	1.04	0.69	1.04	0.69	1.04	V
		V _{CC} = 3.0 V	0.88	-	1.24	0.88	1.24	0.88	1.24	V
V _H	hysteresis voltage	(V _{T+} - V _{T-}); see <u>Fig. 4</u> , <u>Fig. 5</u> , <u>Fig. 6</u> and <u>Fig. 7</u>								
		V _{CC} = 0.8 V	0.07	-	0.50	0.07	0.50	0.07	0.50	V
		V _{CC} = 1.1 V	0.08	-	0.46	0.08	0.46	0.08	0.46	V
		V _{CC} = 1.4 V	0.18	-	0.56	0.18	0.56	0.18	0.56	V
		V _{CC} = 1.65 V	0.27	-	0.66	0.27	0.66	0.27	0.66	V
		V _{CC} = 2.3 V	0.53	-	0.92	0.53	0.92	0.53	0.92	V
		V _{CC} = 3.0 V	0.79	-	1.31	0.79	1.31	0.79	1.31	V

11.2. Waveforms transfer characteristics



Low-power 2-input NAND Schmitt trigger



12. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Fig. 9.

Symbol	Parameter	Conditions		25 °C		-40 °C to	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Typ [1]	Мах	Min	Max	Min	Max	
C _L = 5 p	F	,							1	
t _{pd}	propagation	A or B to Y; see Fig. 8 [2]								
de	delay	V _{CC} = 0.8 V	-	22.5	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	6.3	13.4	2.4	15.1	2.4	16.6	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.6	8.2	1.9	9.7	1.9	10.7	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.9	6.6	1.7	7.9	1.7	8.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	3.2	5.3	1.5	6.2	1.5	6.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.6	2.9	4.7	1.4	5.6	1.4	6.2	ns
C _L = 10	pF									
t _{pd}	propagation	A or B to Y; see Fig. 8 [2]								
	delay	V _{CC} = 0.8 V	-	26.1	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.0	7.2	15.4	2.7	17.3	2.7	19.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	5.2	9.3	2.2	11.0	2.2	12.1	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.5	7.5	2.0	9.0	2.0	9.9	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.8	6.1	1.8	7.2	1.8	7.9	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.5	5.5	1.8	6.5	1.8	7.2	ns
C _L = 15	pF	,								
t _{pd}	propagation	A or B to Y; see Fig. 8 [2]								
	delay	V _{CC} = 0.8 V	-	29.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.3	8.0	17.2	3.0	19.4	3.0	21.3	ns
		V _{CC} = 1.4 V to 1.6 V	2.8	5.8	10.4	2.5	12.3	2.5	13.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	5.0	8.3	2.3	10.0	2.3	11.0	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	4.2	6.7	2.1	7.9	2.1	8.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	3.9	6.1	2.0	7.3	2.0	8.0	ns

74AUP1G132

Low-power 2-input NAND Schmitt trigger

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	-40 °C to	o +125 °C	Unit
			Min	Typ [1]	Max	Min	Мах	Min	Max	
C _L = 30	pF	,								
t _{pd}	propagation	A or B to Y; see Fig. 8 [2]								
	delay	V _{CC} = 0.8 V	-	39.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	10.2	22.6	3.8	25.4	3.8	27.9	ns
		V _{CC} = 1.4 V to 1.6 V	3.6	7.3	13.3	3.2	15.8	3.2	17.4	ns
		V _{CC} = 1.65 V to 1.95 V	3.2	6.3	10.6	2.9	12.8	2.9	14.1	ns
		V _{CC} = 2.3 V to 2.7 V	3.0	5.3	8.5	2.7	10.1	2.7	11.1	ns
		V _{CC} = 3.0 V to 3.6 V	2.8	5.0	7.8	2.7	9.2	2.7	10.1	ns
C _L = 5 p	F, 10 pF, 15 pF	F and 30 pF		· · · · · ·		•				
C _{PD}	power dissipation	$f_i = 1 \text{ MHz};$ [3] V _I = GND to V _{CC}								
	capacitance	V _{CC} = 0.8 V	-	2.6	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.9	-	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.2	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.8	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.4	-	-	-	-	-	pF

All typical values are measured at nominal V_{CC} . [1]

[2] [3]

 t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W). $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

fo = output frequency in MHz;

 C_{L} = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

12.1. Waveforms and test circuit

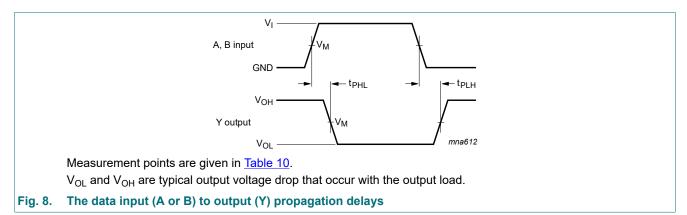


Table 10. Measurement points

Supply voltage	Output	Input				
V _{CC}	V _M	V_{M} V_{I} $t_{r} = t_{f}$				
0.8 V to 3.6 V	0.5 × V _{CC}	$0.5 \times V_{CC}$	V _{CC}	≤ 3.0 ns		

Low-power 2-input NAND Schmitt trigger

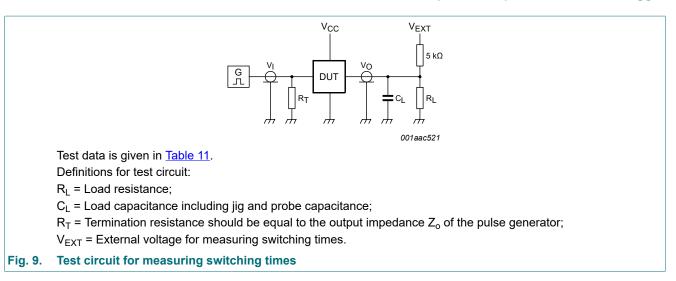


Table 11. Test data

Supply voltage	Load		V _{EXT}		
V _{cc}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	$5 \text{ k}\Omega$ or $1 \text{ M}\Omega$	open	GND	$2 \times V_{CC}$

[1] For measuring enable and disable times $R_L = 5 k\Omega$.

For measuring propagation delays, setup and hold times and pulse width R_L = 1 M Ω .

74AUP1G132

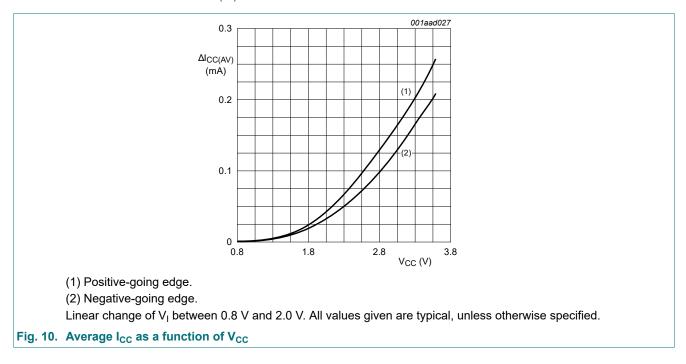
13. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

 $\mathsf{P}_{\mathsf{add}} = \mathsf{f}_{\mathsf{i}} \times (\mathsf{t}_{\mathsf{r}} \times \Delta \mathsf{I}_{\mathsf{CC}(\mathsf{AV})} + \mathsf{t}_{\mathsf{f}} \times \Delta \mathsf{I}_{\mathsf{CC}(\mathsf{AV})}) \times \mathsf{V}_{\mathsf{CC}} \text{ where:}$

- P_{add} = additional power dissipation (µW);
- f_i = input frequency (MHz);
- t_r = input rise time (ns); 10 % to 90 %;
- t_f = input fall time (ns); 90 % to 10 %;
- ΔI_{CC(AV)} = average additional supply current (µA).

Average $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Fig. 10.



14. Package outline

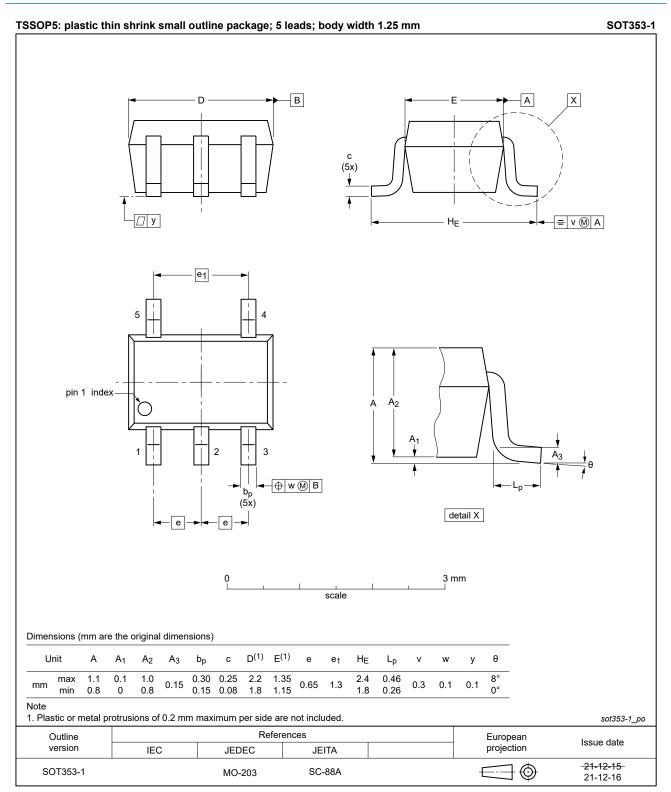


Fig. 11. Package outline SOT353-1 (TSSOP5)

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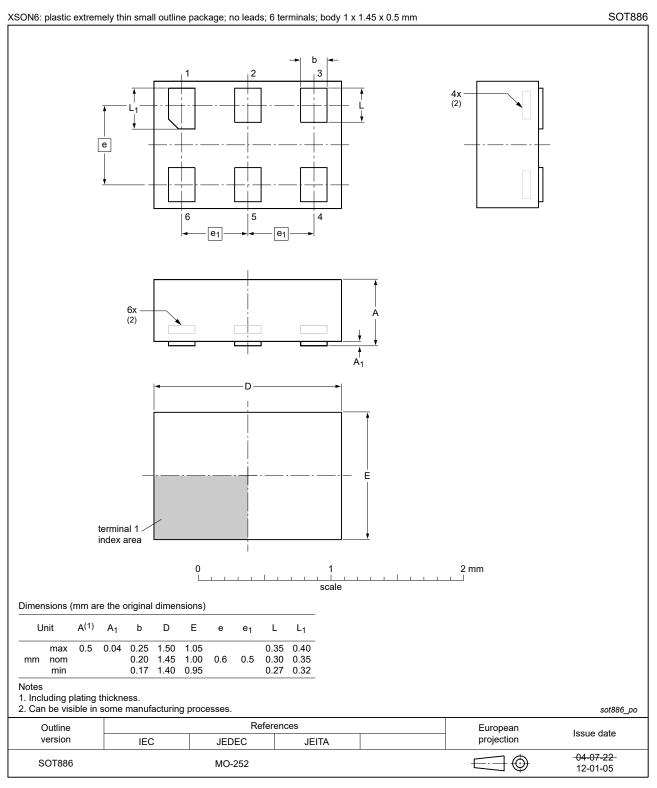
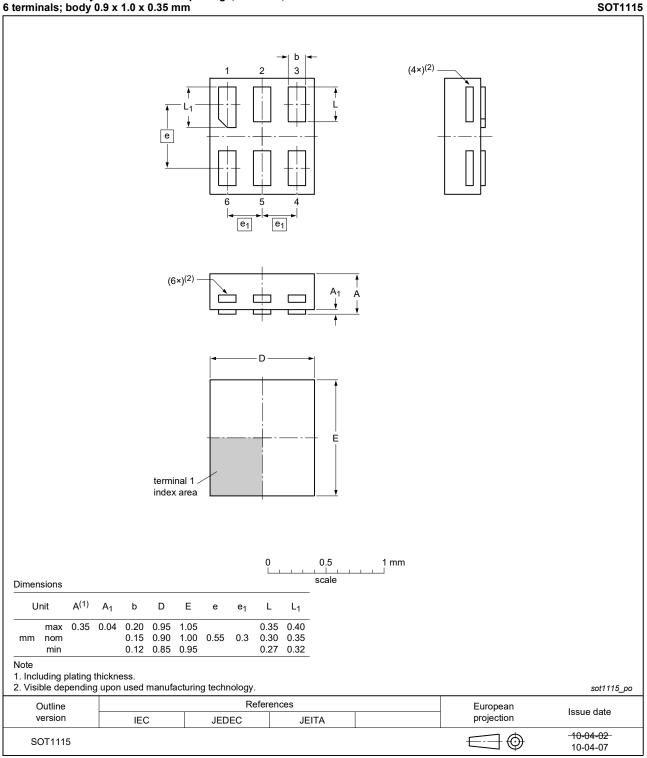


Fig. 12. Package outline SOT886 (XSON6)

Low-power 2-input NAND Schmitt trigger

XSON6: extremely thin small outline package; no leads; 6 terminals; body 0.9 x 1.0 x 0.35 mm





SOT1202

Low-power 2-input NAND Schmitt trigger

XSON6: extremely thin small outline package; no leads;	
6 terminals; body 1.0 x 1.0 x 0.35 mm	

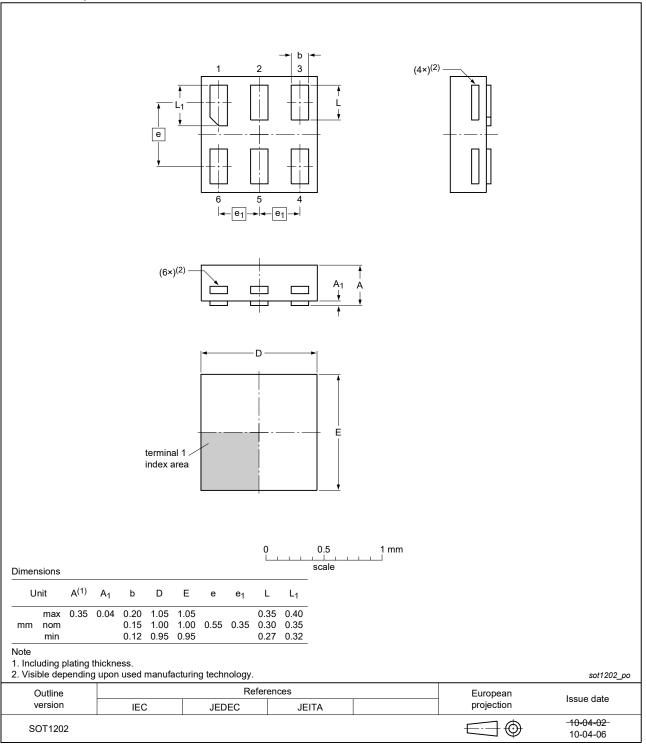
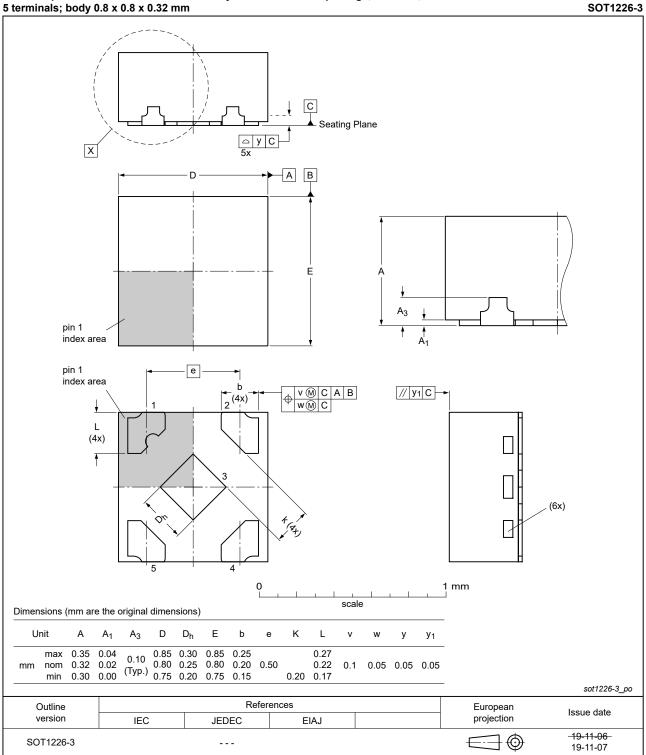


Fig. 14. Package outline SOT1202 (XSON6)

Low-power 2-input NAND Schmitt trigger



X2SON5: plastic thermal enhanced extremely thin small outline package; no leads; 5 terminals; body 0.8 x 0.8 x 0.32 mm

Fig. 15. Package outline SOT1226-3 (X2SON5)

15. Abbreviations

Table 12. Abbreviations		
Acronym	Description	
CDM	Charged Device Model	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
HBM	Human Body Model	

16. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP1G132 v.9.1	20230711	Product data sheet	-	74AUP1G132 v.8
Modifications:	<u>Section 2</u> : E	SD specification updated	according to the lat	est JEDEC standard.
74AUP1G132 v.8	20220114	Product data sheet	-	74AUP1G132 v.7
Modifications:	• <u>Fig. 11</u> : Pac	kage outline drawing for S	SOT353-1 (TSSOP5) has changed.
74AUP1G132 v.7	20210709	Product data sheet	-	74AUP1G132 v.6
Modifications:	 Type number Section 1 ar 	K2SON5) package change er 74AUP1G132GF (SOT and <u>Section 2</u> updated. rating values for P _{tot} total	891) removed.	
74AUP1G132 v.6	20190501	Product data sheet	-	74AUP1G132 v.5
Modifications:	of Nexperia Legal texts 		new company nam	nply with the identity guideline e where appropriate.
74AUP1G132 v.5	20120629	Product data sheet	-	74AUP1G132 v.4
Modifications:		number 74AUP1G132GX tline drawing of SOT886 (· ,	
74AUP1G132 v.4	20111124	Product data sheet	-	74AUP1G132 v.3
Modifications:	Legal pages	updated.		
74AUP1G132 v.3	20101029	Product data sheet	-	74AUP1G132 v.2
74AUP1G132 v.2	20090615	Product data sheet	-	74AUP1G132 v.1
74AUP1G132 v.1	20061020	Product data sheet	-	-

17. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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Product data sheet

Contents

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Ordering information	2
5. Marking	
6. Functional diagram	2
7. Pinning information	3
7.1. Pinning	3
7.2. Pin description	3
8. Functional description	4
9. Limiting values	4
10. Recommended operating conditions	4
11. Static characteristics	5
11.1. Transfer characteristics	7
11.2. Waveforms transfer characteristics	7
12. Dynamic characteristics	8
12.1. Waveforms and test circuit	9
13. Application information	11
14. Package outline	
15. Abbreviations	
16. Revision history	17
17. Legal information	

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